

Product Summary

BV _{DSS}	R _{DS(on)} Max	I _D T _A = +25°C
-40V	60mΩ @ V _{GS} = -10V	-6.4A
	100mΩ @ V _{GS} = -4.5V	-5.6A

Description and Applications

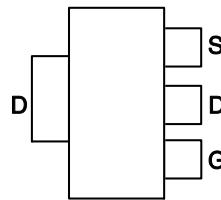
This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- DC-DC converters
- Disconnect switches
- Audio output stages
- Motor controls

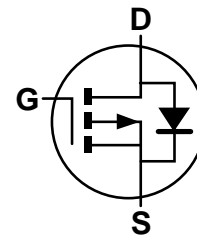
SOT223 (Type DN)



Top View



Pin Out - Top View



Equivalent Circuit

Features and Benefits

- Low On-Resistance
- Fast Switching Speed
- Low Threshold
- Low Gate Drive
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The ZXMP4A16GQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

Mechanical Data

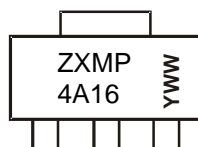
- Package: SOT223
- Package Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.112 grams (Approximate)

Ordering Information (Note 4)

Part Number	Package	Packing	
		Qty.	Carrier
ZXMP4A16GQTA	SOT223 (Type DN)	1,000	Tape & Reel
ZXMP4A16GQTC	SOT223 (Type DN)	4,000	Tape & Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



ZXMP4A16 = Product Type Marking Code
 YWW = Date Code Marking
 Y = Year (ex: 4 = 2024)
 WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit	
Drain-Source Voltage			V _{DSS}	-40	V	
Gate-Source Voltage			V _{GS}	±20	V	
Continuous Drain Current	V _{GS} = 10V	(Note 6)	I _D	-6.4	A	
		T _A = +70°C (Note 6)		-4.6		
		(Note 5)		-1.7		
Pulsed Drain Current	V _{GS} = 10V	(Note 7)	I _{DM}	-21	A	
Continuous Source Current (Body Diode)			(Note 6)	I _S	-5.2	A
Pulsed Source Current (Body Diode)			(Note 7)	I _{SM}	-21	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

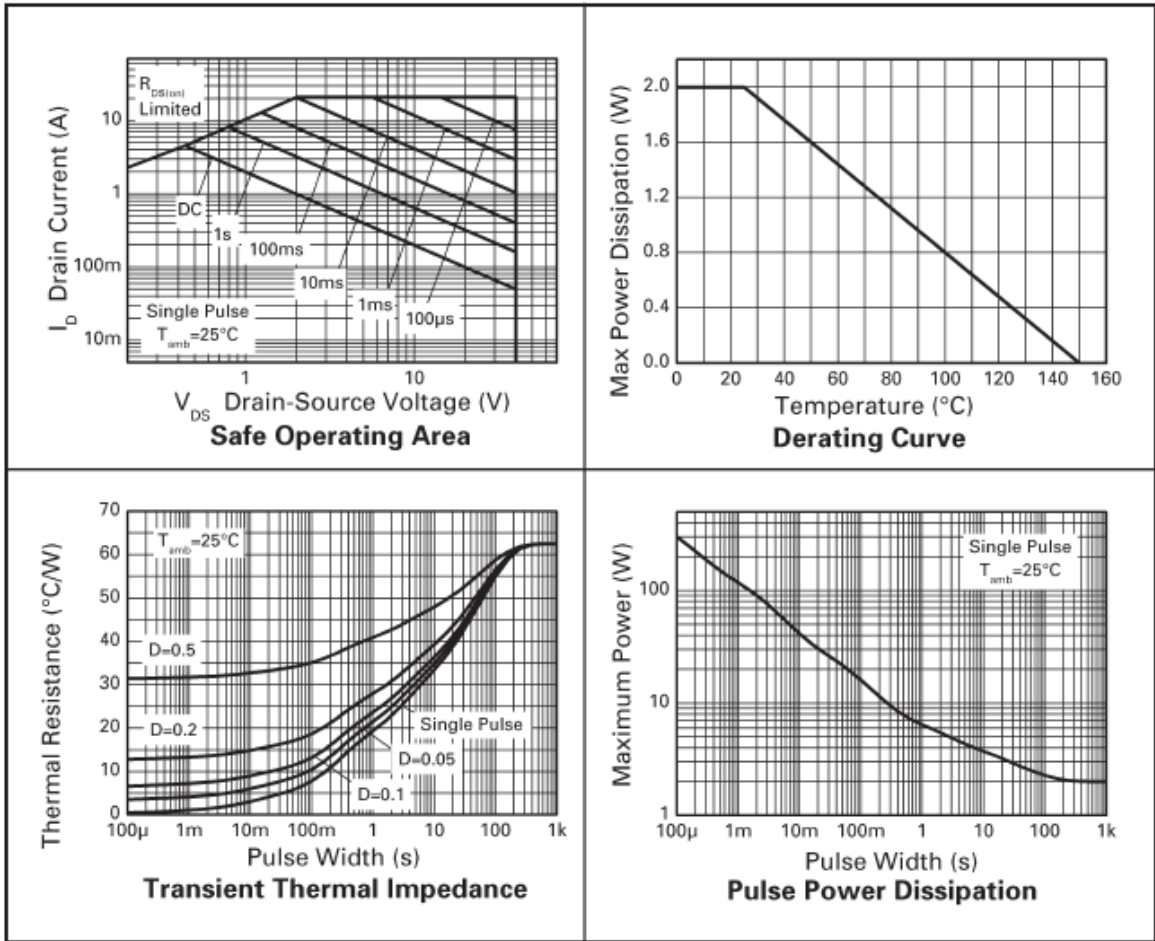
Characteristic			Symbol	Value	Unit
Power Dissipation	(Note 5)	P _D	P _D	2.0	W
				16	
Linear Derating Factor	(Note 6)	R _{θJA}	R _{θJA}	3.9	mW/°C
				31	
Thermal Resistance, Junction to Ambient	(Note 5)	R _{θJA}	R _{θJA}	62.5	°C/W
	(Note 6)			32.2	
Operating and Storage Temperature Range			T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

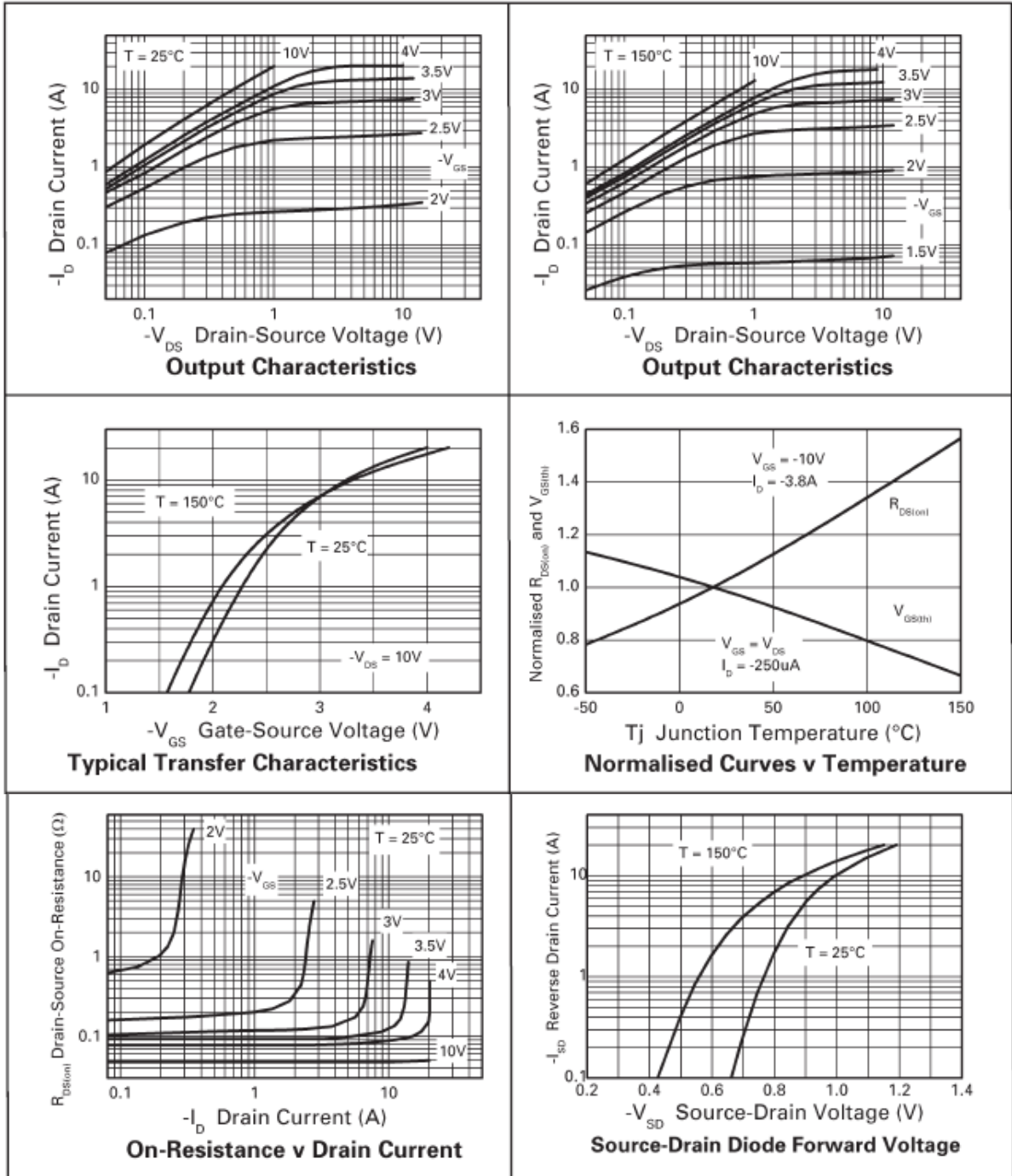
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	-40	—	—	V	I _D = -250μA, V _{GS} = 0V
Zero Gate Voltage Drain Current	I _{DSS}	—	—	-1	μA	V _{DS} = -40V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	—	—	100	nA	V _{GS} = ±20V, V _{DS} = 0V
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(th)}	-1.0	—	—	V	I _D = -250μA, V _{DS} = V _{GS}
Static Drain-Source On-Resistance (Note 8)	R _{DS(on)}	—	—	60	mΩ	V _{GS} = -10V, I _D = -3.8A
				100		V _{GS} = -4.5V, I _D = -2.9A
Forward Transconductance (Notes 8 & 10)	g _{fs}	—	8.85	—	S	V _{DS} = -15V, I _D = -3.8A
Diode Forward Voltage (Note 8)	V _{SD}	—	-0.85	-1.2	V	T _J = +25°C, I _S = -3.4A, V _{GS} = 0V
Reverse Recovery Time (Note 10)	t _{rr}	—	27.2	—	ns	T _J = +25°C, I _F = -3A,
Reverse Recovery Charge (Note 10)	Q _{rr}	—	25.4	—	nC	di/dt = 100A/μs
DYNAMIC CHARACTERISTICS (Note 10)						
Input Capacitance	C _{iss}	—	1007	—	pF	V _{DS} = -20V, V _{GS} = 0V f = 1MHz
Output Capacitance	C _{oss}	—	130	—	pF	
Reverse Transfer Capacitance	C _{rss}	—	85	—	pF	
Total Gate Charge (Note 9)	Q _g	—	13.6	—	nC	V _{GS} = -5V
Total Gate Charge (Note 9)	Q _g	—	26.1	—	nC	V _{DS} = -20V I _D = -3.8A
Gate-Source Charge (Note 9)	Q _{gs}	—	2.8	—	nC	
Gate-Drain Charge (Note 9)	Q _{gd}	—	4.8	—	nC	V _{DD} = -20V, V _{GS} = -10V, I _D = -1A, R _G = 6.0Ω
Turn-On Delay Time (Note 9)	t _{D(on)}	—	3.0	—	ns	
Turn-On Rise Time (Note 9)	t _r	—	3.5	—	ns	
Turn-Off Delay Time (Note 9)	t _{D(off)}	—	13.4	—	ns	
Turn-Off Fall Time (Note 9)	t _f	—	7.2	—	ns	

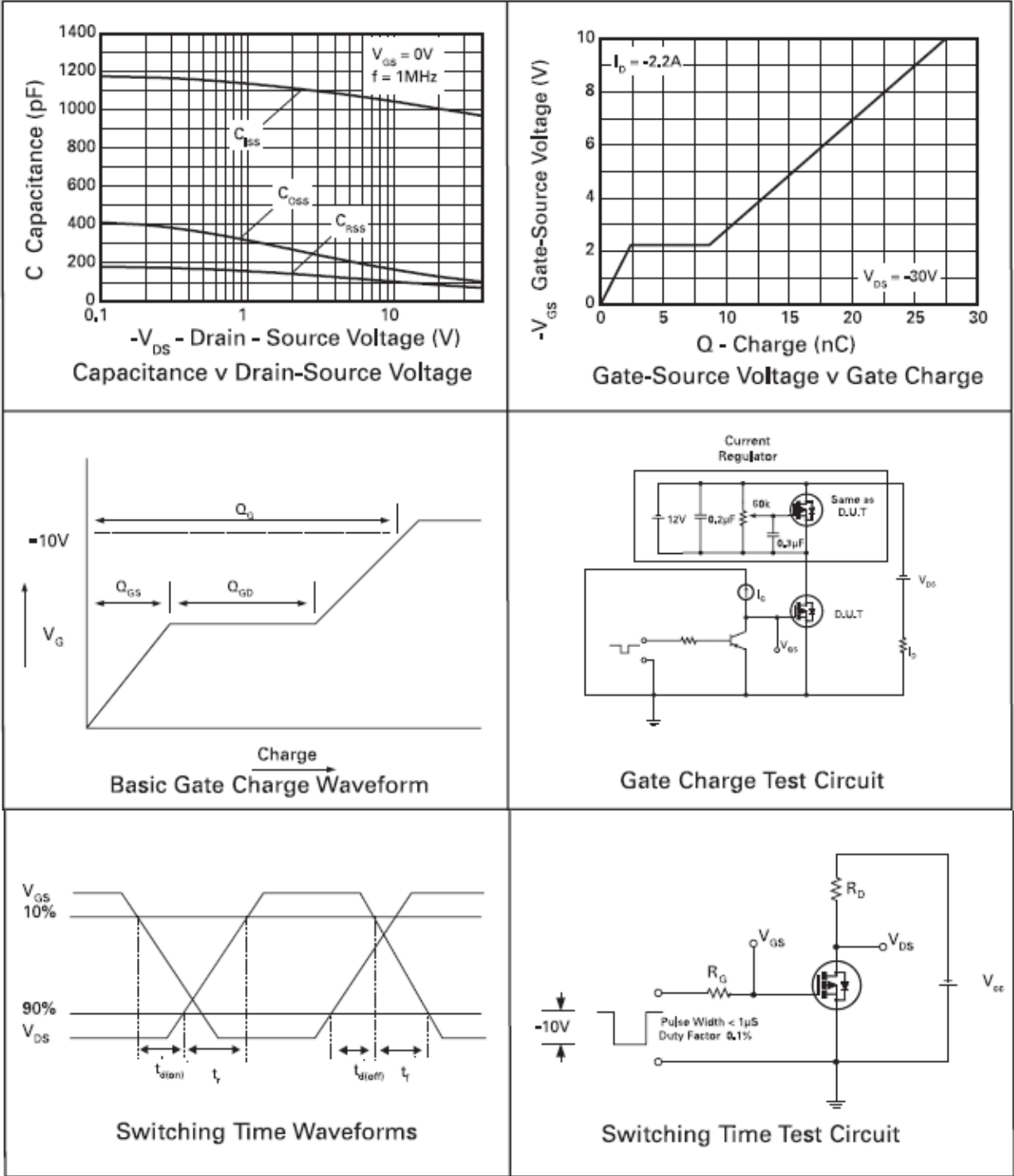
- Notes:
5. For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
 6. For a device surface mounted on FR4 PCB measured at t ≤ 10 seconds.
 7. For a device surface mounted on 25mm x 25mm FR4 PCB, D = 0.05 pulse width limited by maximum junction temperature.
 8. Measured under pulsed conditions. Width ≤ 300μs. Duty cycle ≤ 2%.
 9. Switching characteristics are independent of operating junction temperature.
 10. For design aid only, not subject to production testing.

CHARACTERISTICS



TYPICAL CHARACTERISTICS

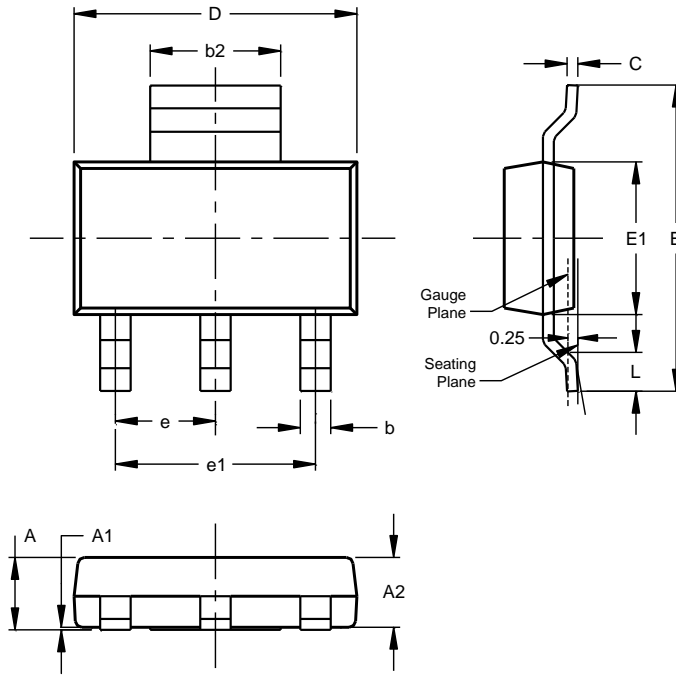




Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)



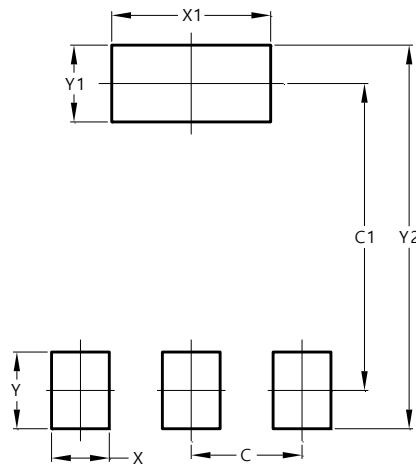
SOT223 (Type DN)			
Dim	Min	Max	Typ
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--

All Dimensions in mm

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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